


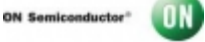






	<h2 style="color: red;">NSBC114YDPDXV6T1</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">NSBC114YDPDXV6T1</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	TRANS PREBIAS NPN/PNP SOT563
<b>Datenblätter:</b>	 <a href="#">NSBC114YDPDXV6T1.pdf</a>	
<b>RoHs Status:</b>	Enthält Blei / RoHS nicht konform	
<b>Lagerzustand:</b>	New original, 32640 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	NSBC114YDPDXV6T1
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN/PNP SOT563
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	32640 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	1 NPN, 1 PNP - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	80 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)

NSBC114YDPDXV6T1 ist neu im Original, Suche NSBC114YDPDXV6T1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSBC114YDPDXV6T1 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSBC114YDPDXV6T1: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>NSBC114YDPDXV</b> ON NSBC114YDPDXV ON	 <b>NSBC115EPDXV6T1G</b> AMI Semiconductor / ON Semiconductor SS SOT563 RSTR XSTR TR	 <b>NSBC114YDXV6T5</b> ON NSBC114YDXV6T5 ON	 <b>NSBC114YDPDXV6T5G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563
 <b>NSBC114YDPDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563	 <b>NSBC115EDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563	 <b>NSBC114YF3T5G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 254MW SOT1123	 <b>NSBC114YDXV6T5G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563

### heiße Teile

Mehr

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DD25F.60	LTC3689IUD#TRPBF	MAX4764TB	NSB1706DMW5T1G	NSB4904DW1T1G
NSB8JT-E3/31	NSB9435T1	NSB9435T1G	NSBA114EDP6T5G	NSBA114EDXV6T1
NSBA114YDXV6T1	NSBA123JDXV6T1	NSBA123JDXV6T1G	NSBA123JDXV6T5G	NSBA143TDXV6T1G
NSBA144EDP6T5G	NSBC114EDXV6T1	NSBC114EDXV6T1G	NSBC114EPDXV6T1G	NSBC114EPDXV6T5
NSBC114TDXV6T1	NSBC114YDP6T5G	NSBC114YDXV6T1	NSBC114YDXV6T1G	NSBC114YDXV6T5
NSBC115EDXV6T1	NSBC123JDXV6T1	NSBC123JPDV6T1	NSBC123JPDV6T1G	NSBC124EPDXV6T1
NSBC124EPDXV6T5	NSBC124XPDXV6T1	NSBC143EDXV6T5	NSBC143ZPDV6T1G	NSBC143ZPDV6T5
NSBC144EDXV6T1	NSBC144EDXV6T1G	NSBC144EDXV6T5	NSBC144EDXV6T5G	NSBC144EPDXV6T1
NSBC144EPDXV6T1G	RFG60N10	SKY77460-13	TMK063CH090FP-F	UPA2718GR-E2

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